

HD74LVC139

Dual 2-to-4-line Decoders / Demultiplexers

REJ03D0350-0300Z (Previous ADE-205-069B (Z)) Rev.3.00 Jul. 23, 2004

Description

The HD74LVC139 has two independent two-to-four-line decoders each with a single active low enable input in a 16 pin package. Data on the select inputs cause one of the four normally high outputs to go low. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V}$
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V)
- Typical V_{OL} ground bounce < 0.8 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@ V_{CC} = 3.3 V, Ta = 25°C)
- High output current ± 24 mA (@V_{CC} = 3.0 V to 5.5 V)
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC139FPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74LVC139TELL	TSSOP-16 pin	TTP-16DAV	Т	ELL (2,000 pcs/reel)

Note: Please consult the sales office for the above package availability.

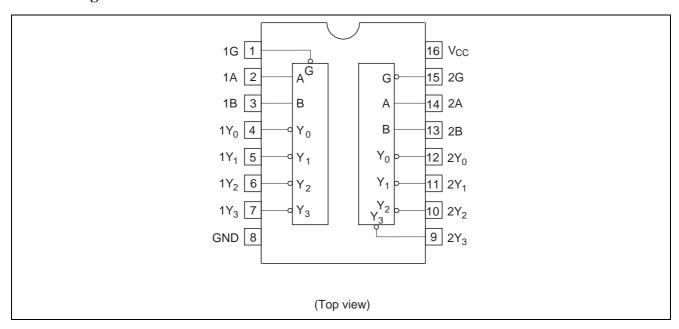
Function Table

Input

Enable	Select		Outputs	Outputs					
G	В	Α	Y ₀	Y ₁	Y ₂	Y ₃			
Н	Х	Х	Н	Н	Н	Н			
L	L	L	L	Н	Н	Н			
L	L	Н	Н	L	Н	Н			
L	Н	L	Н	Н	L	Н			
L	Н	Н	Н	Н	Н	L			

H: High levelL: Low levelX: Immaterial

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	-0.5 to 6.0	V	
Input diode current	I _{IK}	-50	mA	$V_1 = -0.5 \text{ V}$
Input voltage	VI	-0.5 to 6.0	V	
Output diode current	I _{OK}	-50	mA	$V_{O} = -0.5 \text{ V}$
		50		$V_O = V_{CC} + 0.5 \text{ V}$
Output voltage	Vo	-0.5 to V_{CC} +0.5	V	
Output current	lo	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	100	mA	
Storage temperature	Tstg	-65 to 150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{CC}	1.5 to 5.5	V	Data retention
		2.0 to 5.5		At operation
Input / output voltage	VI	0 to 5.5	V	G, A, B
	Vo	0 to V _{CC}	V	Y_0 to Y_3
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	– 12	mA	$V_{CC} = 2.7 \text{ V}$
		-24 ^{*2}		V _{CC} = 3.0 V to 5.5 V
	I _{OL}	12	mA	V _{CC} = 2.7 V
		24 *2		V _{CC} = 3.0 V to 5.5 V
Input rise / fall time *1	t _r , t _f	10	ns/V	

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

2. Duty cycle $\leq 50\%$

Electrical Characteristics

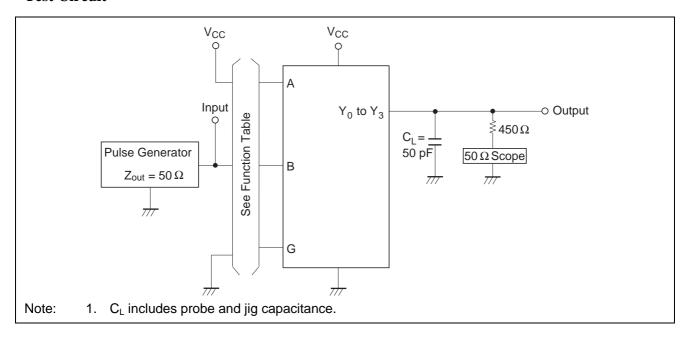
Ta = -40 t	o 85°C

		1a = -40 to 65 C					
Item	Symbol	V _{CC} (V)	Min	Max	Unit	Test Conditions	
Input voltage	V _{IH}	2.7 to 3.6	2.0	_	V		
		4.5 to 5.5	V _{CC} ×0.7	_	_		
	V _{IL}	2.7 to 3.6	_	0.8	V		
		4.5 to 5.5	_	V _{CC} ×0.3	_		
Output voltage	V_{OH}	2.7 to 5.5	V _{CC} -0.2	_	V	$I_{OH} = -100 \mu A$	
		2.7	2.2	_	_	$I_{OH} = -12 \text{ mA}$	
		3.0	2.4		_		
		3.0	2.0	_	_	$I_{OH} = -24 \text{ mA}$	
		4.5	3.8	_	_		
	V _{OL}	2.7 to 5.5	_	0.2	V	$I_{OL} = 100 \mu A$	
		2.7	_	0.4	_	I _{OL} = 12 mA	
		3.0		0.55	_	I _{OL} = 24 mA	
		4.5	_	0.55	_		
Input current	I _{IN}	0 to 5.5	_	±5.0	μΑ	V _{IN} = 5.5 V or GND	
Quiescent supply current	I _{CC}	5.5		20	μA	$V_{IN} = V_{CC}$ or GND	
	ΔI_{CC}	3.0 to 3.6	_	500	μΑ	V_{IN} = one input at $(V_{CC} - 0.6)V$, other inputs at V_{CC} or GND	

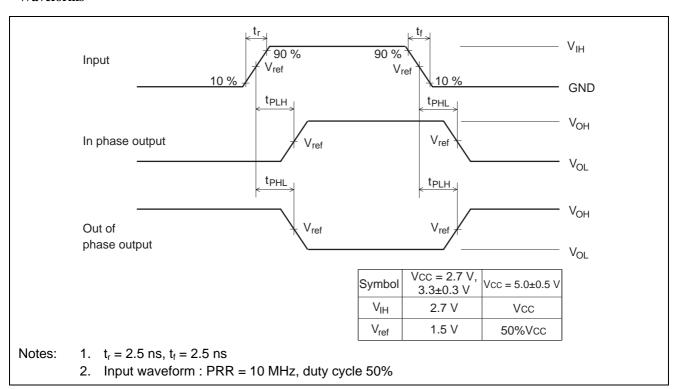
Switching Characteristics

				Ta = -40 to	85°C		From	То
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	2.7	_	7.0	10.0	ns	G, A, B	Y ₀ to Y ₃
	t_{PHL}	3.3±0.3	1.5	5.0	9.0			
		5.0±0.5	_	3.5	7.5			
Input capacitance	C _{IN}	2.7	_	3.0	_	pF		
Output capacitance	Co	2.7	_	15.0		pF		

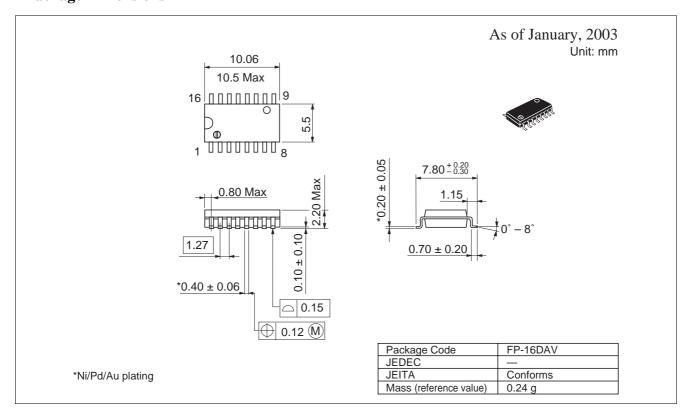
Test Circuit

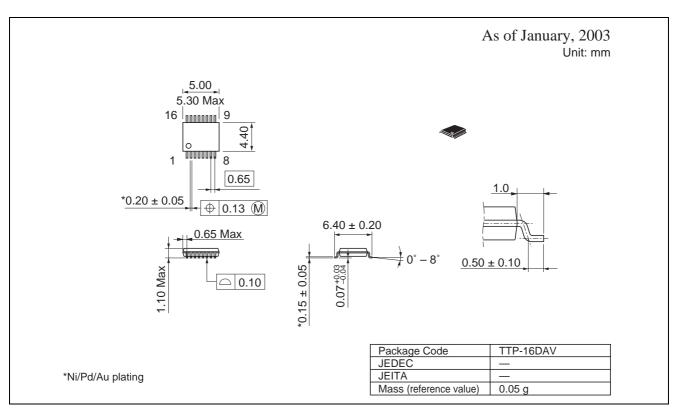


Waveforms



Package Dimensions





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